



AiP74LVC1G79

Single D-type flip-flop; positive-edge trigger

Product Specification

Specification Revision History:

Version	Date	Description
2017-12-A1	2017-12	New
2021-09-A2	2021-09	Modify ambient temperature to -40℃~+105℃ and add electrical characteristics of -40℃~+105℃
2021-10-A3	2021-10	Modify ordering information
2021-12-A4	2021-12	Modify ordering information
2022-03-A5	2022-03	Modify ordering information note 1



1、General Description

The AiP74LVC1G79 provides a single positive-edge triggered D-type flip-flop.

Information on the data input is transferred to the Q-output on the LOW-to-HIGH transition of the clock pulse. The D-input must be stable one set-up time prior to the LOW-to-HIGH clock transition for predictable operation.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device in a mixed 3.3V and 5V environment.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

Features:

- Wide supply voltage range from 1.65V to 5.5V
- ± 24 mA output drive ($V_{CC}=3.0V$)
- CMOS low power consumption
- Direct interface with TTL levels
- Inputs accept voltages up to 5V
- Specified from $-40^{\circ}C$ to $+105^{\circ}C$
- Packaging information: SOT23-5/SOT353

Ordering Information:

Reel packing specifications:

Part number	Packaging form	Marking code	Reel quantity	Boxed reel quantity	Notes
AiP74LVC1G79GB235.TR	SOT23-5	CUXX	3000 PCS/reel	30000 PCS/box	Dimensions of plastic enclosure: 2.9mm×1.6mm Pin spacing:0.95mm
AiP74LVC1G79GC353.TR	SOT353	CUXX	3000 PCS/reel	30000 PCS/box	Dimensions of plastic enclosure: 2.1mm×1.3mm Pin spacing:0.65mm

Note 1: “XX” refers to variable content, meaning year and package batch serial number.

Note 2: If the physical information is inconsistent with the ordering information, please refer to the actual product.



2、Block Diagram And Pin Description

2.1、Block Diagram

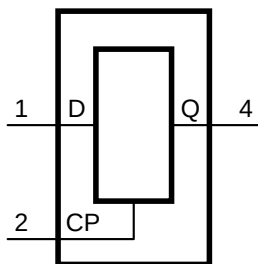


Figure 1. Logic symbol

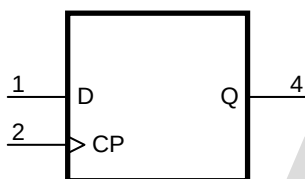


Figure 2. IEC logic symbol

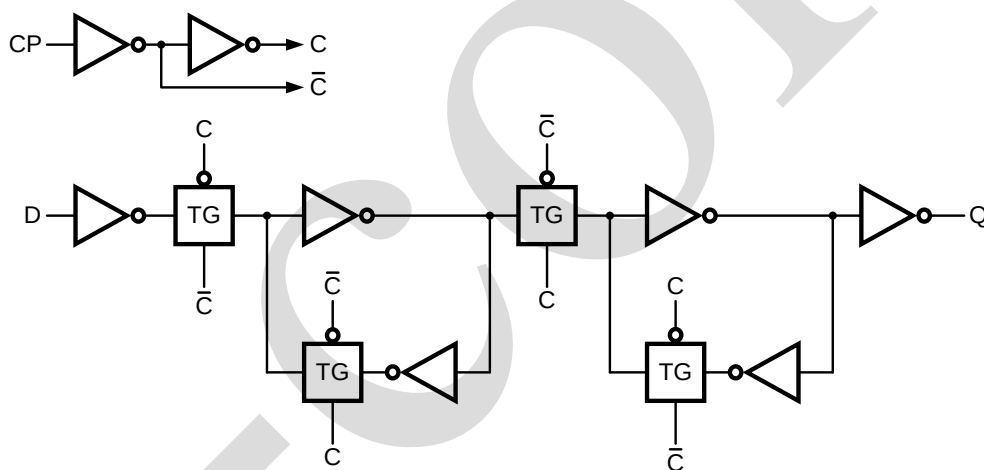
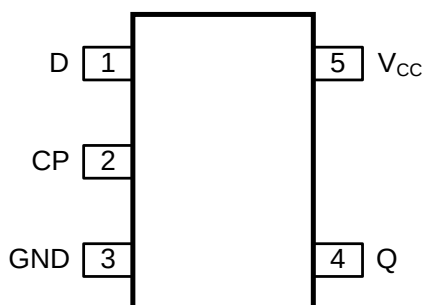


Figure 3. Logic diagram

2.2、Pin Configurations





2.3、Pin Description

Pin No.	Pin Name	Description
1	D	data input
2	CP	clock pulse input
3	GND	ground (0V)
4	Q	data output
5	V _{CC}	supply voltage

2.4、Function Table

Input		Output
CP	D	Q
↑	L	L
↑	H	H
L	X	q

Note:

H=HIGH voltage level;

L=LOW voltage level;

↑=LOW-to-HIGH CP transition;

X=don't care;

q=lower case letter indicates the state of referenced input, one set-up time prior to the LOW-to-HIGH CP transition.

3、Electrical Parameter

3.1、Absolute Maximum Ratings

(Voltages are referenced to GND (ground=0V), unless otherwise specified)

Characteristic	Symbol	Conditions	Min.	Max.	Unit
supply voltage	V _{CC}	-	-0.5	+6.5	V
input clamping current	I _{IK}	V _I <0V	-50	-	mA
input voltage	V _I	-	-0.5	+6.5	V
output clamping current	I _{OK}	V _O <0V or V _O >V _{CC}	-	±50	mA
output voltage	V _O	Active mode	-0.5	V _{CC} +0.5	V
		Power-down mode	-0.5	+6.5	V
output current	I _O	V _O =0V to V _{CC}	-	±50	mA
supply current	I _{CC}	-	-	100	mA
ground current	I _{GND}	-	-100	-	mA
storage temperature	T _{stg}	-	-65	+150	°C
total power dissipation	P _{tot}	T _{amb} =-40°C to +105°C	-	250	mW
soldering temperature	T _L	10s	250		°C



3.2、Recommended Operating Conditions

(Voltages are referenced to GND (ground=0V), unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	1.65	-	5.5	V
input voltage	V_I	-	0	-	5.5	V
output voltage	V_O	Active mode	0	-	V_{CC}	V
		$V_{CC}=0V$; Power-down mode	0	-	5.5	V
ambient temperature	T_{amb}	-	-40	-	+105	°C
input transition rise and fall rate	$\Delta t/\Delta V$	$V_{CC}=1.65V$ to $2.7V$	-	-	20	ns/V
		$V_{CC}=2.7V$ to $5.5V$	-	-	10	ns/V

3.3、Electrical Characteristics

3.3.1、DC Characteristics 1

($T_{amb}=-40^{\circ}C$ to $+85^{\circ}C$, voltages are referenced to GND (ground=0V), unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Typ. ^[1]	Max.	Unit
HIGH-level input voltage	V _{IH}	V _{CC} =1.65V to 1.95V		0.65×V _{CC}	-	-	V
		V _{CC} =2.3V to 2.7V		1.7	-	-	V
		V _{CC} =2.7V to 3.6V		2.0	-	-	V
		V _{CC} =4.5V to 5.5V		0.7×V _{CC}	-	-	V
LOW-level input voltage	V _{IL}	V _{CC} =1.65V to 1.95V		-	-	0.35×V _{CC}	V
		V _{CC} =2.3V to 2.7V		-	-	0.7	V
		V _{CC} =2.7V to 3.6V		-	-	0.8	V
		V _{CC} =4.5V to 5.5V		-	-	0.3×V _{CC}	V
HIGH-level output voltage	V _{OH}	V _I =V _{IH} or V _{IL}	I _O =-100uA; V _{CC} =1.65V to 5.5V	V _{CC} -0.1	-	-	V
			I _O =-4mA; V _{CC} =1.65V	1.2	-	-	V
			I _O =-8mA; V _{CC} =2.3V	1.9	-	-	V
			I _O =-12mA; V _{CC} =2.7V	2.2	-	-	V
			I _O =-24mA; V _{CC} =3.0V	2.3	-	-	V
			I _O =-32mA; V _{CC} =4.5V	3.8	-	-	V
LOW-level output voltage	V _{OL}	V _I =V _{IH} or V _{IL}	I _O =100uA; V _{CC} =1.65V to 5.5V	-	-	0.1	V
			I _O =4mA; V _{CC} =1.65V	-	-	0.45	V
			I _O =8mA; V _{CC} =2.3V	-	-	0.3	V
			I _O =12mA; V _{CC} =2.7V	-	-	0.4	V
			I _O =24mA; V _{CC} =3.0V	-	-	0.55	V
			I _O =32mA; V _{CC} =4.5V	-	-	0.55	V
input leakage current	I _I	V _I =5.5V or GND; V _{CC} =0V to 5.5V		-	±0.1	±1	uA
power-off leakage current	I _{OFF}	V _{CC} =0V; V _I or V _O =5.5V		-	±0.1	±2	uA
supply current	I _{CC}	V _I =5.5V or GND; V _{CC} =1.65V to 5.5V; I _O =0A		-	0.1	4	uA
additional supply current	ΔI _{CC}	per pin; V _{CC} =2.3V to 5.5V; V _I =V _{CC} -0.6V; I _O =0A		-	5	500	uA



input capacitance	C_I	$V_{CC}=3.3V$; $V_I=GND$ to V_{CC}	-	5	-	pF
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Note:

[1] All typical values are measured at $V_{CC}=3.3V$ and $T_{amb}=25^{\circ}C$.

3.3.2、DC Characteristics 2

($T_{amb}=-40^{\circ}C$ to $+105^{\circ}C$, voltages are referenced to GND (ground=0V), unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Typ. ^[1]	Max.	Unit
HIGH-level input voltage	V _{IH}	V _{CC} =1.65V to 1.95V		0.65×V _{CC}	-	-	V
		V _{CC} =2.3V to 2.7V		1.7	-	-	V
		V _{CC} =2.7V to 3.6V		2.0	-	-	V
		V _{CC} =4.5V to 5.5V		0.7×V _{CC}	-	-	V
LOW-level input voltage	V _{IL}	V _{CC} =1.65V to 1.95V		-	-	0.35×V _{CC}	V
		V _{CC} =2.3V to 2.7V		-	-	0.7	V
		V _{CC} =2.7V to 3.6V		-	-	0.8	V
		V _{CC} =4.5V to 5.5V		-	-	0.3×V _{CC}	V
HIGH-level output voltage	V _{OH}	V _I =V _{IH} or V _{IL}	I _O =-100uA; V _{CC} =1.65V to 5.5V	V _{CC} -0.1	-	-	V
			I _O =-4mA; V _{CC} =1.65V	0.95	-	-	V
			I _O =-8mA; V _{CC} =2.3V	1.7	-	-	V
			I _O =-12mA; V _{CC} =2.7V	1.9	-	-	V
			I _O =-24mA; V _{CC} =3.0V	2.0	-	-	V
			I _O =-32mA; V _{CC} =4.5V	3.4	-	-	V
LOW-level output voltage	V _{OL}	V _I =V _{IH} or V _{IL}	I _O =100uA; V _{CC} =1.65V to 5.5V	-	-	0.1	V
			I _O =4mA; V _{CC} =1.65V	-	-	0.7	V
			I _O =8mA; V _{CC} =2.3V	-	-	0.45	V
			I _O =12mA; V _{CC} =2.7V	-	-	0.6	V
			I _O =24mA; V _{CC} =3.0V	-	-	0.8	V
			I _O =32mA; V _{CC} =4.5V	-	-	0.8	V
input leakage current	I _I	V _I =5.5V or GND; V _{CC} =0V to 5.5V		-	-	±1	uA
power-off leakage current	I _{OFF}	V _{CC} =0V; V _I or V _O =5.5V		-	-	±2	uA
supply current	I _{CC}	V _I =5.5V or GND; V _{CC} =1.65V to 5.5V; I _O =0A		-	-	4	uA
additional supply current	ΔI _{CC}	per pin; V _{CC} =2.3V to 5.5V; V _I =V _{CC} -0.6V; I _O =0A		-	-	500	uA

Note:

[1] All typical values are measured at $V_{CC}=3.3V$ and $T_{amb}=25^{\circ}C$.

**3.3.3、AC Characteristics 1**(T_{amb}=-40°C to +85°C, voltages are referenced to GND (ground=0V), unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ. ^[1]	Max	Unit
propagation delay	t _{pd}	CP to Q; see Figure 5 ^[2]	V _{CC} =1.65V to 1.95V	1.0	3.6	9.9 ns
			V _{CC} =2.3V to 2.7V	0.5	2.3	7.0 ns
			V _{CC} =2.7V	0.5	2.6	6.0 ns
			V _{CC} =3.0V to 3.6V	0.5	2.2	5.0 ns
			V _{CC} =4.5V to 5.5V	0.5	1.7	3.8 ns
set-up time	t _{su}	D to CP; see Figure 6	V _{CC} =1.65V to 1.95V	2.5	1.4	- ns
			V _{CC} =2.3V to 2.7V	1.7	0.9	- ns
			V _{CC} =2.7V	1.7	0.9	- ns
			V _{CC} =3.0V to 3.6V	1.3	0.6	- ns
			V _{CC} =4.5V to 5.5V	1.2	0.6	- ns
hold time	t _h	D to CP; see Figure 6	V _{CC} =1.65V to 1.95V	0	-0.7	- ns
			V _{CC} =2.3V to 2.7V	0	-0.4	- ns
			V _{CC} =2.7V	+0.5	-0.3	- ns
			V _{CC} =3.0V to 3.6V	+0.5	-0.3	- ns
			V _{CC} =4.5V to 5.5V	+0.5	-0.2	- ns
pulse width	t _w	CP HIGH or LOW; see Figure 6	V _{CC} =1.65V to 1.95V	3.0	1.1	- ns
			V _{CC} =2.3V to 2.7V	2.5	0.7	- ns
			V _{CC} =2.7V	2.5	0.6	- ns
			V _{CC} =3.0V to 3.6V	2.5	0.6	- ns
			V _{CC} =4.5V to 5.5V	2.0	0.5	- ns
maximum frequency	f _{max}	CP; see Figure 6	V _{CC} =1.65V to 1.95V	160	250	- MHz
			V _{CC} =2.3V to 2.7V	160	300	- MHz
			V _{CC} =2.7V	160	350	- MHz
			V _{CC} =3.0V to 3.6V	160	450	- MHz
			V _{CC} =4.5V to 5.5V	200	500	- MHz
power dissipation capacitance	C _{PD}	V _I =GND to V _{CC} ; V _{CC} =3.3V ^[3]		-	17	- pF

Note:

[1] Typical values are measured at T_{amb}=25°C and V_{CC}=1.8V, 2.5V, 2.7V, 3.3V and 5.0V respectively.[2] t_{pd} is the same as t_{PLH} and t_{PHL}.[3] C_{PD} is used to determine the dynamic power dissipation (P_D in uW). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:f_i=input frequency in MHz; f_o=output frequency in MHz;C_L=output load capacitance in pF;V_{CC}=supply voltage in V;

N=number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$ =sum of outputs.



3.3.4、AC Characteristics 2

($T_{amb}=-40^{\circ}\text{C}$ to $+105^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Typ. ^[1]	Max	Unit
propagation delay	t _{pd}	CP to Q; see Figure 5 ^[2]	V _{CC} =1.65V to 1.95V	1.0	-	12.5	ns
			V _{CC} =2.3V to 2.7V	0.5	-	9.0	ns
			V _{CC} =2.7V	0.5	-	8.0	ns
			V _{CC} =3.0V to 3.6V	0.5	-	6.5	ns
			V _{CC} =4.5V to 5.5V	0.5	-	5.0	ns
set-up time	t _{su}	D to CP; see Figure 6	V _{CC} =1.65V to 1.95V	2.5	-	-	ns
			V _{CC} =2.3V to 2.7V	1.7	-	-	ns
			V _{CC} =2.7V	1.7	-	-	ns
			V _{CC} =3.0V to 3.6V	1.2	-	-	ns
			V _{CC} =4.5V to 5.5V	1.2	-	-	ns
hold time	t _h	D to CP; see Figure 6	V _{CC} =1.65V to 1.95V	0	-	-	ns
			V _{CC} =2.3V to 2.7V	0	-	-	ns
			V _{CC} =2.7V	+0.5	-	-	ns
			V _{CC} =3.0V to 3.6V	+0.5	-	-	ns
			V _{CC} =4.5V to 5.5V	+0.5	-	-	ns
pulse width	t _w	CP HIGH or LOW; see Figure 6	V _{CC} =1.65V to 1.95V	3.0	-	-	ns
			V _{CC} =2.3V to 2.7V	2.5	-	-	ns
			V _{CC} =2.7V	2.5	-	-	ns
			V _{CC} =3.0V to 3.6V	2.5	-	-	ns
			V _{CC} =4.5V to 5.5V	2.0	-	-	ns
maximum frequency	f _{max}	CP; see Figure 6	V _{CC} =1.65V to 1.95V	160	-	-	MHz
			V _{CC} =2.3V to 2.7V	160	-	-	MHz
			V _{CC} =2.7V	160	-	-	MHz
			V _{CC} =3.0V to 3.6V	160	-	-	MHz
			V _{CC} =4.5V to 5.5V	200	-	-	MHz

Note:

[1] Typical values are measured at $T_{amb}=25^{\circ}\text{C}$ and $V_{CC}=1.8\text{V}$, 2.5V , 2.7V , 3.3V and 5.0V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .



4、Testing Circuit

4.1、AC Testing Circuit

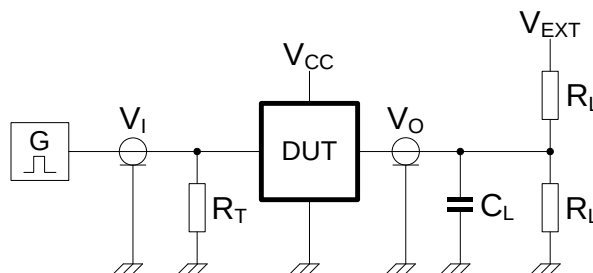


Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

R_L =Load resistance.

C_L =Load capacitance including jig and probe capacitance.

R_T =Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} =External voltage for measuring switching times.

4.2、AC Testing Waveforms

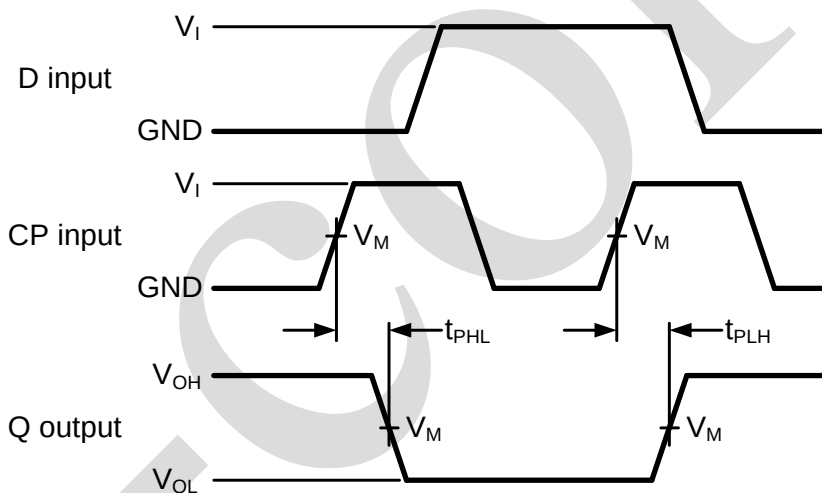


Figure 5. Clock (CP) to output (Q) propagation delay times

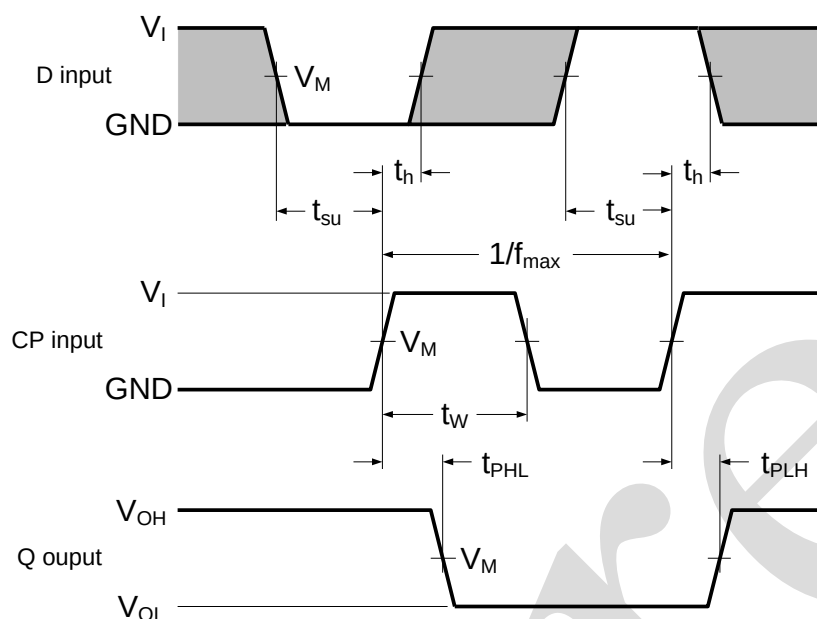


Figure 6. Clock (CP) to output (Q) propagation delay times, clock pulse width, D to set-up times, the CP to D hold times and maximum clock pulse frequency

4.3、Measurement Points

Supply voltage	Input	Output
V_{CC}	V_M	V_M
1.65V to 1.95V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.3V to 2.7V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.7V	1.5V	1.5V
3.0V to 3.6V	1.5V	1.5V
4.5V to 5.5V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$

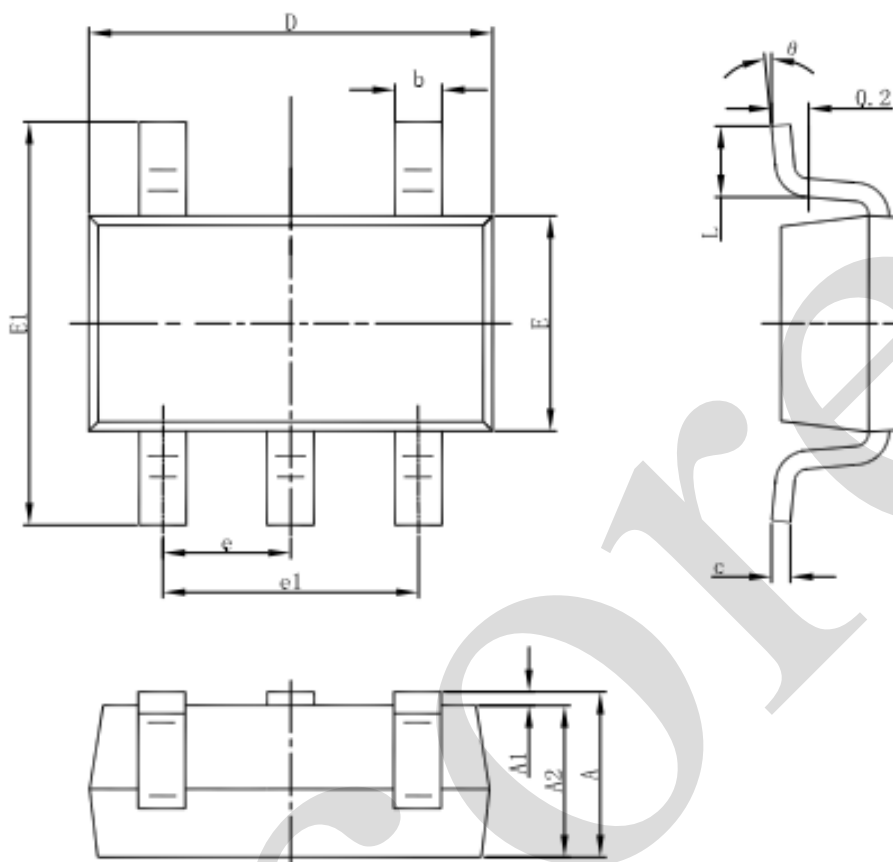
4.4、Test Data

Supply voltage	Input		Load		V_{EXT}
V_{CC}	V_I	$t_r = t_f$	C_L	R_L	t_{PLH}, t_{PHL}
1.65V to 1.95V	V_{CC}	$\leq 2.0ns$	30pF	1k Ω	open
2.3V to 2.7V	V_{CC}	$\leq 2.0ns$	30pF	500 Ω	open
2.7V	2.7V	$\leq 2.5ns$	50pF	500 Ω	open
3.0V to 3.6V	2.7V	$\leq 2.5ns$	50pF	500 Ω	open
4.5V to 5.5V	V_{CC}	$\leq 2.5ns$	50pF	500 Ω	open



5、Package Information

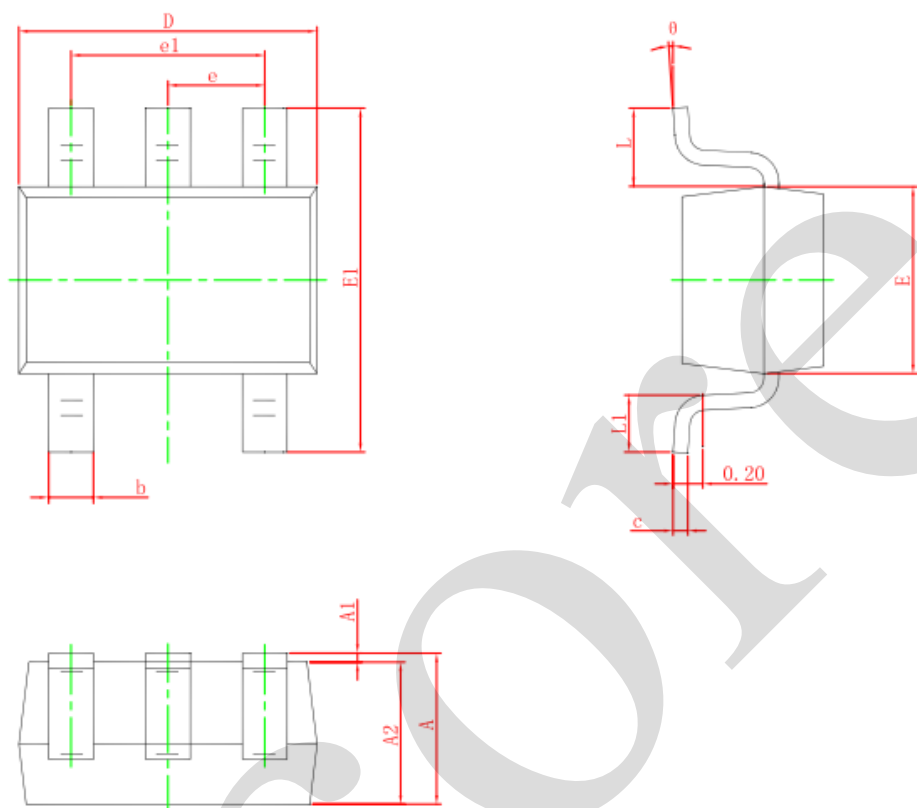
5.1、SOT23-5



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°



5.2、SOT353



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP.		0.026 TYP.	
e1	1.200	1.400	0.047	0.055
L	0.525 REF.		0.021 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°



6、Statements And Notes

6.1、The name and content of Hazardous substances or Elements in the product

Part name	Hazardous substances or Elements									
	Lead and lead compounds	Mercury and mercury compounds	Cadmium and cadmium compounds	Hexavalent chromium compounds	Polybrominated biphenyls	Polybrominated biphenyl ethers	Dibutyl phthalate	Butylbenzyl phthalate	Di-2-ethylhexyl phthalate	Diisobutyl phthalate
Lead frame	○	○	○	○	○	○	○	○	○	○
Plastic resin	○	○	○	○	○	○	○	○	○	○
Chip	○	○	○	○	○	○	○	○	○	○
The lead	○	○	○	○	○	○	○	○	○	○
Plastic sheet installed	○	○	○	○	○	○	○	○	○	○
explanation	○: Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. ×: Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements.									

6.2、Notion

Recommended carefully reading this information before the use of this product;

The information in this document are subject to change without notice;

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